NSN 5961-00-418-6544

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Inclosure Material:

Metal

Overall Length:

0.080 inches

Overall Diameter:

0.260 inches

Internal Configuration:

Junction contact

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open and 15.0 emitter to base voltage, dc and 1.5 breakdown voltage,

emitter-to-base, collector open

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current

Power Rating Per Characteristic:

360.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Leads gold and leads silver

Precious Material:

Gold and silver

Test Data Document:

00752-334762 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0